

Disentangle RF Amplifier Specs: Intermodulation Distortion and Intercept Points



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When selecting an amplifier, designers need to understand what distortion components the amplifier will exhibit when stimulated by a signal with two or more closely spaced frequency components. For common linear amplifiers, this distortion is typically represented in the data sheet as intermodulation distortion (IMD) between two test frequencies. However, for radio frequency (RF)-oriented amplifiers such as low-noise amplifiers (LNAs), RF power amplifiers (PAs) and RF gain blocks, an intercept point (IP) spec often represents two-tone distortion, referred to as either the input (IIP) or output (OIP). As linear and RF amplifier speeds blend together in modern high-speed amplifiers such as the [LMH6401](#) variable gain amplifier, it is important to understand how the two specs are related and the manner in which they reflect device performance.

Let's first look at IMD, because it is the simpler of the two specs. When the amplifier is stimulated by a two-tone signal of frequencies f_1 and f_2 , it creates harmonic-distortion products at frequencies nf_1 and nf_2 , and also creates intermodulation products at $nf_1 - f_2, nf_1 + f_2, nf_2 - f_1$, and $nf_2 + f_1$ where n is an integer starting at 1. Similar to harmonic products, the total intermodulation product spectrum is typically dominated by second- and third-order components because the higher orders are usually comparatively low in power. (For this reason, I will only focus on discussing the second- and third-order intermodulation components:

$f_1 \pm f_2, f_2 \pm f_1$ and $2f_1 \pm f_2, 2f_2 \pm f_1$, respectively.) The IMD value is the difference between the power of one of the input signals (assuming equal power signals) and the desired intermodulation component. [Figure 1](#) shows the visual relationship of both the harmonic-distortion and IMD products.

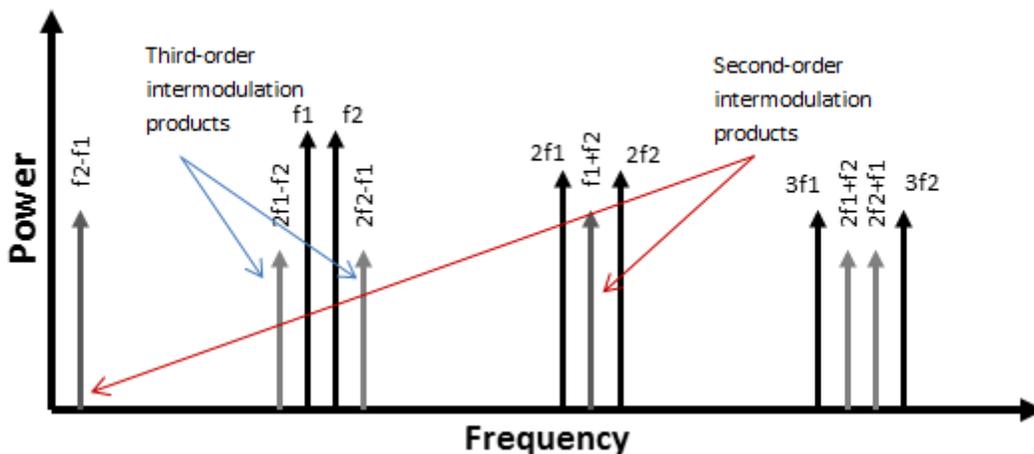


Figure 1. Intermodulation and Harmonic-distortion Products

From the definition, you can see that IMD is merely the difference in power between a fundamental and an n^{th} -order intermodulation product ($IMD_n = P_{\text{fund}} - P_{IMn}$). From here, you can now understand the relationship between the IMD value and the IP.

The IP value, unlike IMD, is not an actual measurement but a mathematical calculation to obtain a figure of merit that describes system linearity. To understand this, first imagine a slightly nonlinear system with a fundamental power gain of 1 and a two-tone stimulus (the same setup used to measure IMD). Since the system is nonlinear,

it will have n^{th} -order intermodulation components that would increase with input power at a ratio of n -to-1. The IP is then defined as the theoretical point at which the n^{th} -order intermodulation product power is equal to the fundamental power.

Figure 2 shows a visual representation of the second- and third-order IPs in relation to the fundamental power, and the respective intermodulation product powers.

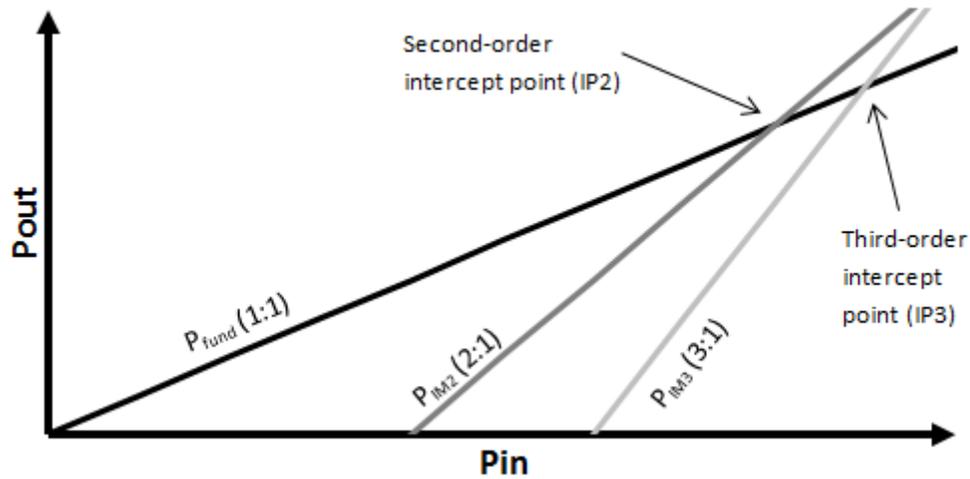


Figure 2. Visual Representation of Intercept Points (IPs)

The IPs are only theoretical because a system will reach a maximum-output power point before it should ever reach the actual IPs. From Figure 2, you can see that a more linear system (e.g., a system with lower-power intermodulation products) will “shift” the intermodulation product lines to the right, thus increasing the value of the IPs.

You can easily calculate the n^{th} -order output intercept using Equation 1:

$$OIP_n = \left(\frac{1}{n-1}\right)(n \cdot P_{ofund} - P_{oIMn}) \quad (1)$$

where n is the order of intercept you are calculating, P_{ofund} is the output power of one fundamental tone and P_{oIMn} is the output power of the n^{th} -order intermodulation product.

This equation can be referred to the input, IIP_n , by subtracting the gain of the system from the OIP_n value.

Using the commonly calculated third-order output IP as an example, Equation 1 becomes Equation 2:

$$OIP_3 = \left(\frac{1}{2}\right)(3 \cdot P_{ofund} - P_{oIM3}) \quad (2)$$

You know that the third-order intermodulation distortion (IMD3) value is equal to $(P_{ofund} - P_{oIM3})$, so you can easily rewrite equation 2 as Equation 3:

$$OIP_3 = P_{ofund} + \frac{IMD3}{2} \quad (3)$$

Using the data sheet of the [TI LMH6401](#) high-speed, variable-gain amplifier, you can use the IMD3 and OIP3 spec numbers to verify Equation 3. At 500MHz, the LMH6401 has an OIP3 value of 40dBm and an IMD3 value of 83dBc, both with -2dBm power per output fundamental tone. Plugging these numbers into Equation 3 yields this result:

$$OIP_3 = -2 + \frac{83}{2} = 39.5 \quad (4)$$

Accounting for 0.5dB of rounding error, you can see that this calculated OIP3 value matches the value given in the datasheet.

I hope these explanations and examples help you now understand the relationship between IMD and IP and how each can be useful toward understanding a system. IMD is a physical measurement that describes the relative power level of IMD components and is useful when you must know the actual power of various components. IP is useful as a figure of merit for the linearity of a system, but does not immediately relate any exact measurement values. Understanding both specifications allows you to have the best understanding of system performance related to two-tone distortion.

Have you ever confused IMD and IP before? What type of issues did it cause in your design? Log in below and leave a comment.

Additional Resources

- Learn more about [TI's high-speed amplifier portfolio](#) and find more technical resources.
- Download the [LMH6401 data sheet](#).
- Read other [high-speed amplifier blog posts](#).
- Learn about TI's entire portfolio of [amplifier ICs](#) and find technical resources.

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